

# isc N-Channel MOSFET Transistor

# IXFA56N30X3

### FEATURES

- Static drain-source on-resistance:
- $R_{DS}(on) \le 27m\Omega@V_{GS}=10V$
- Fully characterized avalanche voltage and current
- 100% Avalanche Tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATION

- Switched mode power supplies
- DC-DC converters

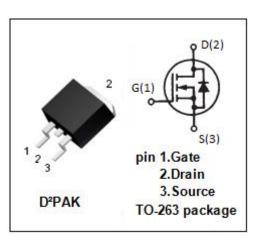
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

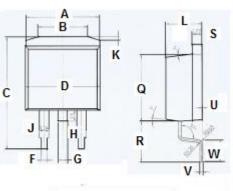
SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	300	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous	56	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	112	А	
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	320	W	
Tj	Operating Junction Temperature	-55~150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	

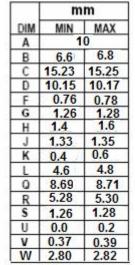
#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	0.39	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V; ID = 1mA	300		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 1.5mA	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 28A		27	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	μA
1035		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;TJ= 125℃		500	PA
$V_{\text{SD}}$	Diode forward voltage	I <sub>F</sub> = 56A; V <sub>GS</sub> = 0V		1.4	V

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